### TOSHIBA DIODE SILICON EPITAXIAL SCHOTTKY BARRIER TYPE

# **1 S S 2 7 1**

### VHF~UHF MIXER APPLICATION

Small Package

Small Delta Forward Voltage :  $\Delta V_F = 10 \text{mV (Max.)}$ 

:  $\Delta C_T = 0.1 pF (Max.)$ Small Delta Total Capacitance

Unit in mm

	29±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02 20±02	α1 θ + α1 β α1 θ + α1 β α1 θ + α0 β α1 θ
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JEDEC		
EIAJ	SC-59	
TOSHIBA	1-3G1G	

Weight: 0.013g

## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	$v_{ m R}$	6	V
Forward Current	$I_{\mathbf{F}}$	30	mA
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$T_{ m stg}$	-55~125	°C

**ELECTRICAL CHARACTERISTICS (Ta = 25)** 

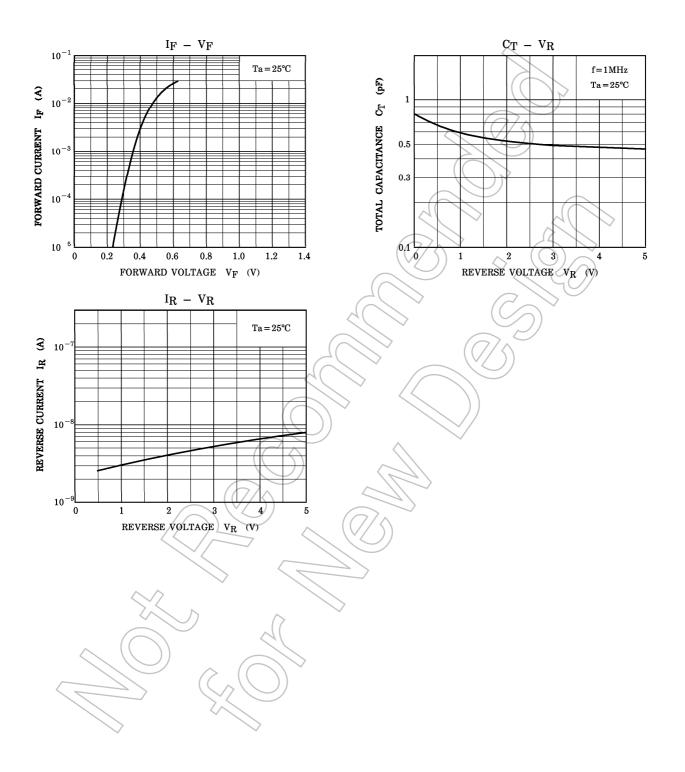
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CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Voltage	$V_{\rm R}$	$I_R = 10 \mu A$	6	_	_	V
Reverse Current	$(I_{\mathbf{R}})$	$V_R=5V$	_	_	0.5	$\mu$ <b>A</b>
Forward Voltage	$V_{\mathbf{F}}(1)$	I <sub>F</sub> =0.1mA	_	0.3	_	V
Forward Voltage	V <sub>F</sub> (2)	$I_{\rm F} = 10 { m mA}$	0.42	0.5	0.55	V
Total Capacitance	$\sim$ C <sub>T</sub>	$V_R = 0V$ , $f = 1MHz$	_	0.8	1.0	pF
Delta Forward Voltage	$\Delta \mathbf{V_F}$	I <sub>F</sub> =10mA (Note)	_	_	10	mV
Delta Total Capacitance	$\Delta C_{\mathrm{T}}$	$V_R = 0V$ , $f = 1MHz$ (Note)	_	_	0.1	pF

(Note): Difference between 2 Devices in 1 Package.

Marking



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